# VS-VSKCS403/100

**Vishay Semiconductors** 



ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 400 A



PRODUCT SUMMARY				
I <sub>F(AV)</sub>	400 A			
V <sub>R</sub>	100 V			
Package	ADD-A-PAK			
Circuit	Two diodes common cathodes			

### **MECHANICAL DESCRIPTION**

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION**

The VS-VSKCS403.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	400	A		
V <sub>RRM</sub>		100	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	20 000	А		
V <sub>F</sub>	200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.83	V		
TJ	Range	-55 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-VSKCS403/100	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	100	N/	
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	V	



Revision: 14-Mar-14

Document Number: 94636

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per module			400		
forward current	per leg	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 111$ °C, rectangular waveform		200	
Maximum peak one cycle		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with	20 000	A	
non-repetitive surge current		IFSM	$10 \text{ ms sine or } 6 \text{ ms rect. pulse}  \text{rated } V_{\text{RRM}} \text{ applied}$	2300		
Non-repetitive avalanche energ	у	E <sub>AS</sub>	$E_{AS}$ T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V <sub>FM</sub>	200 A	T <sub>J</sub> = 25 °C	0.99	v
Maximum forward voltage drop		400 A		1.3	
Maximum forward voltage drop		200 A	- T <sub>J</sub> = 125 °C	0.83	
		400 A		1.09	
Maximum rovaraa laakaga aurrant		T <sub>J</sub> = 25 °C	V Deted V	6	mA
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	80	ША
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		5500	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.26	°C/W
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>		0.1	0/00
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the		Nm
	busbar		spread of the compound.	3	
Case style			JEDEC®	TO-240AA co	ompatible



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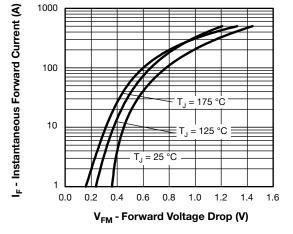


Fig. 1 - Maximum Forward Voltage Drop Characteristics

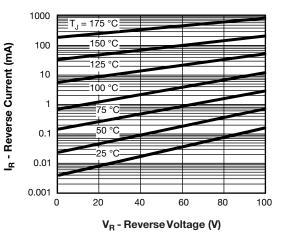


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

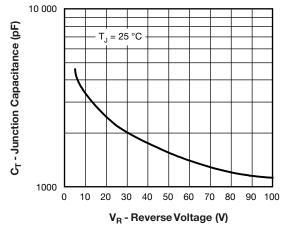
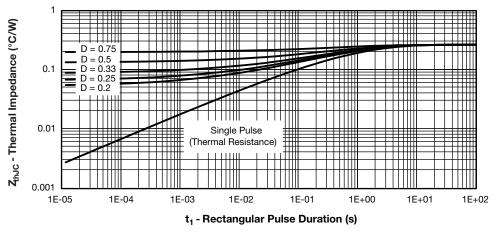


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





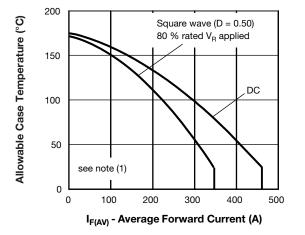
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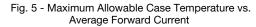
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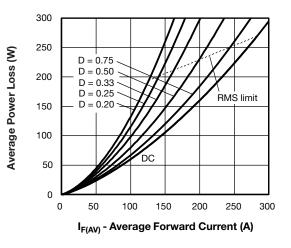


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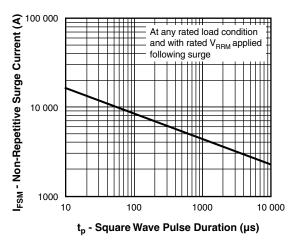


Fig. 7 - Maximum Non-Repetitive Surge Current

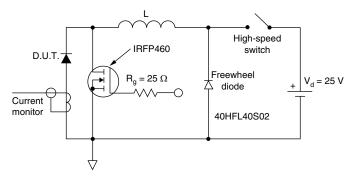


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} =$  Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1} = 80$ % rated  $V_R$ 

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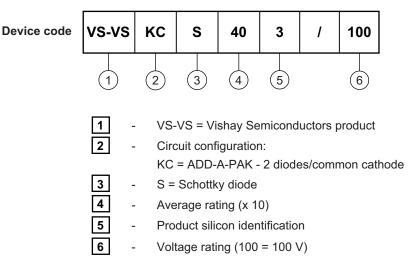
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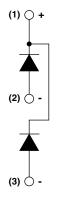
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### **ORDERING INFORMATION TABLE**



#### CIRCUIT CONFIGURATION



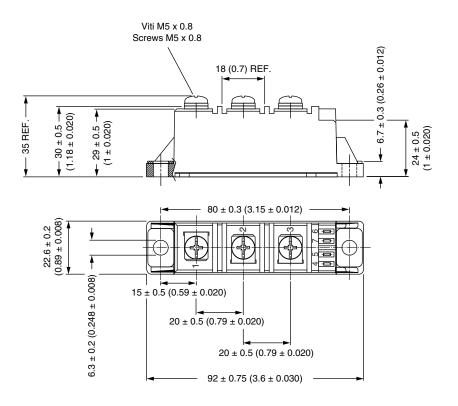
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		

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## **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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